

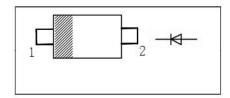
MMSD914WS

Silicon Epitaxial Planar Switching Diode

Features

- Small package
- · Low forward voltage
- · Fast reverse recovery time
- · Small total capacitance

PIN	DESCRIPTION			
1	Cathode			
2	Anode			



Applications

· Ultra high speed switching application

Marking Code: 5D SOD-323 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

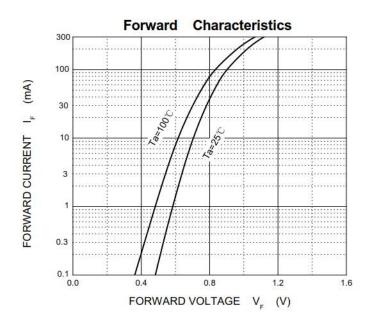
Parameter	Symbol	Value	Unit	
Reverse Voltage	V _R	100	V	
Forward Current	I _F	200	mA	
Non-repetitive Peak Forward Surge Current (t = 1 μs)	I _{FSM}	I _{FSM} 2		
Power Dissipation	P _{tot}	200	mW	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	T _{stg}	- 55 to + 150	°C	

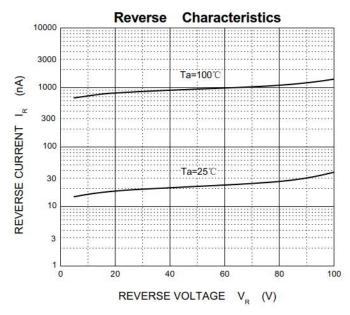
Characteristics at Ta = 25 °C

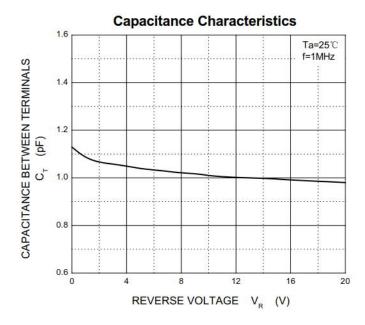
Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F		1	V
Reverse Breakdown Voltage at I _R = 100 μA	V _{(BR)R}	100	-	V
Reverse Current at V _R = 20 V at V _R = 75 V	I _R	B 15	25 5	nΑ μΑ
Reverse Recovery Time at I _F = I _R = 10 mA	t _{rr}		4	ns
Total Capacitance at V _R = 0 , f = 1 MHz	Ст	PER STATE	4	pF

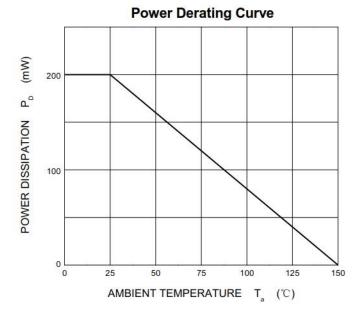


Typical Characteristics Curves



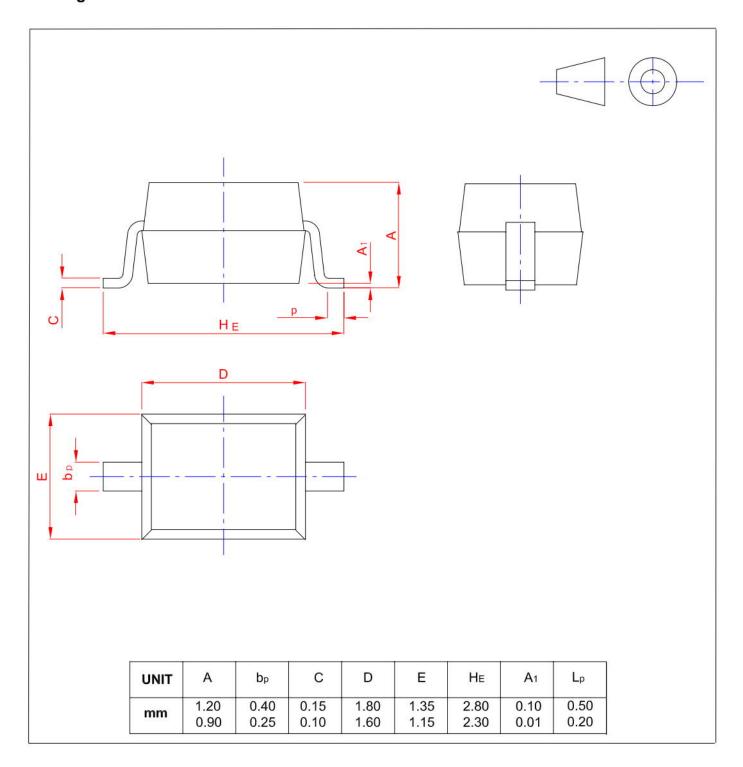








Package Outline SOD-323



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